NSN 5961-01-626-6110

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-626-6110 **Inclosure Material:** Plastic **Overall Length:** Between 0.190 inches and 0.220 inches **Terminal Length:** Between 0.030 inches and 0.060 inches **Overall Height:** Between 0.090 inches and 0.115 inches **Overall Width:** Between 0.080 inches and 0.103 inches **Function For Which Designed:** Bidirectional and transient suppressor **Response Time:** 4.0 nanoseconds 1st semiconductor device diode **Component Name And Quantity:** 1 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon 1st semiconductor device diode Voltage Rating In Volts Per Characteristic: 6.0 working peak reverse voltage 1st semiconductor device diode **Current Rating Per Characteristic:** 38.8 amperes forward current, peak total value 1st semiconductor device diode **Power Rating Per Characteristic:** 400.0 watts peak turn-off power dissipation 1st semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 75.0 degrees celsius ambient air **Product Name:** Smaj transient voltage suppressor diode, bidirectional **Special Features:** Rohs compliant, lead free, ul class 94 v0 **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

Fiig:

A110a0